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# Fault Analysis of Space Station DC Power Systems-Using Neural Network Adaptive Wavelets to Detect Faults

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# FAULT ANALYSIS OF SPACE STATION DC POWER SYSTEMS - USING NEURAL NETWORK ADAPTIVE WAVELETS TO DETECT FAULTS

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## Abstract

This paper describes the application of neural network adaptive wavelets for fault diagnosis of space station power system. The method combines wavelet transform with neural network by incorporating daughter wavelets into weights. Therefore, the wavelet transform and neural network training procedure become one stage, which avoids the complex computation of wavelet parameters and makes the procedure more straightforward. The simulation results show that the proposed method is very efficient for the identification of fault locations.

## INTRODUCTION

Wavelet transform (WT) shows promise for both signal (or image) representation and classification. It has been successfully used in many areas such as optical computation, seismics, acoustics, and mechanical vibrations (Szu 1992, Rioul 1991, and Chui 1992). The representation and classification both can be viewed as feature extraction problems in which the goal is to find a set of daughter wavelets that either best represent the signal or best separate various signal classes in the resulting feature space. For these applications, wavelet analysis overcomes the limitations of Fourier method by employing analysis functions that are local both in time and frequency and allows the convenient representation and classification of duration signals. Recently, several papers have been presented for power system transient signal analysis (Riberio 1994, Santoso 1995, Wilkinson 1996, Pillay 1996, and Momoh 1996). These works focused on the representation of transient signal. An optimization procedure is needed for the calculations of wavelet transform coefficients ( $a_n$ ,  $b_n$ ). This procedure may be time consuming. On the other hand, the best set of wavelets for representation will not necessarily be the same as the best set for classification. As a new tool, wavelets have not been applied to the classification problem of power system.

More recently, Artificial Neural Network (ANN) techniques have been used to solve fault diagnosis problem in power system. The use of neural network based scheme for fault detection and classification is only in its first stage (Chowdhury 1996, and Momoh 1996). In these works, a pre-processing of fault signals by Fast Fourier Transform (FFT) is used. It is a two stage process. The first stage is feature extraction, the second stage is the training of ANN. The disadvantage of this scheme are: (1) The procedure may be time consuming, and (2) FFT technique can be applied with success to steady state phenomena but short-time events require different mathematical tools to aid the analysis.

In this paper, we discuss how wavelet transform coefficients can be adaptively computed in the training stage of ANN. Each daughter wavelet is represented by a weight from input layer to first hidden layer. The neurons of the first hidden layer differ from the neuron of other hidden layers. The inspiration functions of neurons in first hidden layer are linear functions, so that the first hidden layer introduced for wavelet transform can be compressed to the second layer. The wavelet transform coefficients are automatically computed in the training stage of neural network. This neural network adaptive wavelet scheme is applied to the fault diagnosis of space station power system.

The space station power system will provide electrical power to the future space station by converting the solar energy collected from the sun into electrical energy. An AC/DC system architecture is recommended for this special power system.

Figure 1 shows the system structure. The system includes a generator, AC network, an AC/DC converter, DC network, DDCUs and loads. AC system is a generation system which transfers solar energy to electrical energy, while DC system is a distribution system which provides electrical power to all kinds of loads. The generation and distribution systems are connected by an AC/DC converter. Since the time constant of the distribution system is very short, the transient process of the distribution system is very short. Wavelet is, therefore, an efficient choice. The fault diagnosis is carried out for distribution system by the proposed neural network adaptive wavelets. The output current of DDCU is recorded for fault diagnosis.

The simulation results show that the proposed method is very efficient for the identification of the distribution system faults at different locations. The misclassification band for most faults is about 10% -15% of line length from the sending end bus.

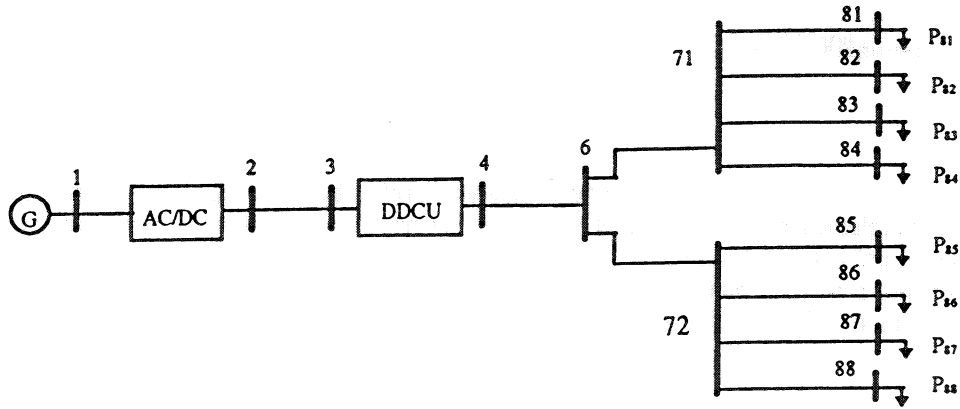


FIGURE 1: Space Station Power System

### NEURAL NETWORK ADAPATIVE WAVELET MODEL

Different models are used for the representation and classification of signals. A short discussion on representation model and classification model is as follows.

#### Representation Model

A signal  $s(t)$  can be approximated by daughters of a mother wavelet  $h(t)$  according to

$$\hat{s}(t) = \sum_{k=1}^{NK} w_k h\left(\frac{t-b_k}{a_k}\right) \quad (1)$$

where the  $\{w_k\}$ ,  $\{b_k\}$  and  $\{a_k\}$  are weight coefficients, shifts, and dilation for each daughter wavelet. Generally, an optimization procedure is used for the calculations of these parameters, which may be time-consuming. In order to speed up the procedure, the approximation of equation (1) can be expressed as the neural network of Figure 2, which contains wavelet nonlinearities ( $f_i = h\left(\frac{t-b_k}{a_k}\right)$ ) in the artificial neurons in hidden layer rather than the standard sigmoidal nonlinearities. The

network parameters  $\{w_k\}$ ,  $\{b_k\}$  and  $\{a_k\}$  can be optimized by minimizing an energy function. This optimization procedure is the same as the procedure for the training of ANN. Therefore, the two optimization procedures can be combined together, i.e., the optimization procedure for wavelet transform is integrated into the optimization procedure of ANN training. The least - mean - squares energy function is employed for signal representation.

$$E = \frac{1}{2} \sum_{i=1}^r [s(t) - \hat{s}(t)]^2 = \frac{1}{2} \sum_{i=1}^r [s(t) - \sum_{k=1}^{NK} w_k h\left(\frac{t-b_k}{a_k}\right)]^2 \quad (2)$$

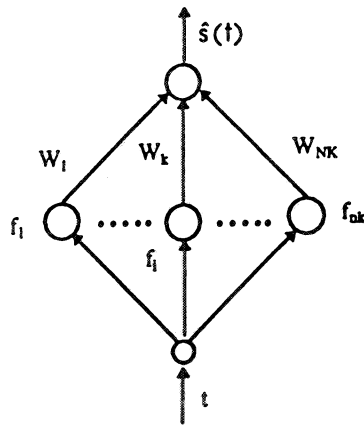


FIGURE 2. Representation Neural Network

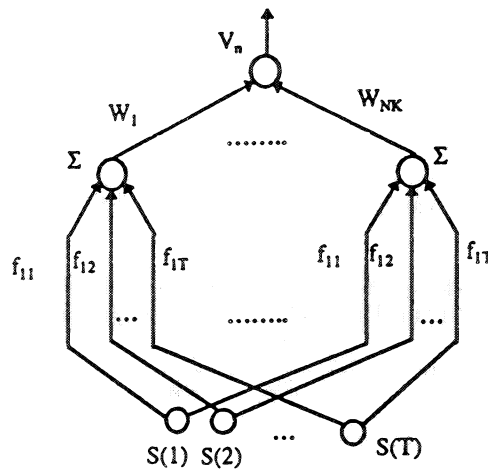


FIGURE 3. Classification Neural Network

**Classification Model**

The extraction of signal features is the vector inner products of a set of wavelets with the input signal. These features can then be input to a classifier. The combined classifier and wavelet feature detector is given by

$$V_n = \sigma(u_n) = \sigma \left[ \sum_{k=1}^{NK} w_k \sum_{i=1}^T s_n(t) h \left( \frac{t-b_k}{a_k} \right) \right] \quad (3)$$

where  $v_n$  is the output for the  $n^{\text{th}}$  training vector  $s_n(t)$  and  $\sigma(z) = \frac{10}{10 + e^{-z}}$ . This classifier can be depicted as the neural network of Figure 3, which uses wavelet weights rather than the wavelet nonlinearities of as in Figure 3. The lower part of Figure 3 produces inner products of the signal which has form of  $\sum_{i=1}^T s_n(t) \cdot h \left( \frac{t-b_k}{a_k} \right)$  and wavelets with the first wavelet on the left and the  $nk^{\text{th}}$  wavelet on the right.

Figure 3 shows two layers of weights.  $f_{ij} = h \left( \frac{t-b_j}{a_j} \right)$  represents the wavelet transform coefficient, while the classification parameters  $\{w_k\}$ ,  $\{a_k\}$  and  $\{b_k\}$  can be optimized by minimizing the error between the calculated and desired outputs.

$$E = \frac{1}{2} \sum_{n=1}^n (d_n - V_n) \quad (4)$$

where  $d_n$  is the desired classifier output for  $s_n(t)$ . It can be set such that  $d_n = 1$  for one class and zero for the other. The classification neural network can be simply represented by Figure 4 (a). The inputs of the ANN are the classified signal values at time intervals ( $t=1, 2, \dots, T$ ). A network with more output elements is shown in Figure 4 (b). The input signals of ANN are the same as the single case. The desired classifier outputs ( $d_1, d_2, \dots, d_n$ ) are set such that

$$\begin{cases} d_i = 1, \text{ if case } i \text{ is true} \\ d_i = 0, \text{ if case } i \text{ is not true} \end{cases}$$

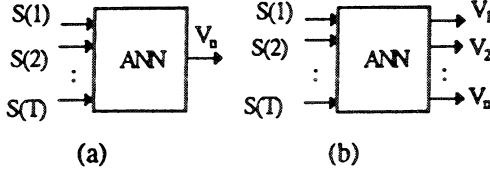


FIGURE 4. Simplified Classification Neural Network

## METHODOLOGY

From the models developed above, it can be seen that only one stage is used for ANN training and extraction of signal features. The feature extraction is integrated in the training process. The algorithm is the same as the standard ANN training algorithm. In our study, the back propagation algorithm (El-Sharkawi 1996) is used.

According to the back propagation algorithm, the network's weights  $\{w_{ij}\}$  are adjusted to minimize the error between desired output and the calculated output. The gradient descent algorithm adapts the weights according to the gradient error, i.e.,

$$\Delta W_{ij} = -\frac{\partial E}{\partial V_j} \cdot \frac{\partial V_j}{\partial W_{ij}} = -\frac{\partial E}{\partial W_{ij}} \quad (5)$$

Specifically, the error signal is defined as

$$\delta_j = \frac{\partial E}{\partial V_j}$$

Equation (5) can be rewritten as

$$\Delta W_{ij} = \mu \delta_j V_i \quad (6)$$

Where  $\mu$  is an adaptability factor and  $\mu > 0$ .

The algorithm for the training of the adaptive wavelets and ANN is shown in Figure 5. The algorithm consists of the following steps.

- (1) Initialization;
- (2) Input classified signal  $S(1), S(2), \dots, S(t)$ , and the desired classifier outputs  $d_i$  ( $i=1, 2, \dots, n$ );
- (3) Calculate the outputs based on the current weights;
- (4) Calculate the error between calculated output and desired output;
- (5) Error check; If convergence is indicated, go to step (6). if not, calculate gradient error and modify weights, go to step (3);
- (6) Output weights and form ANN for fault diagnosis;

When the ANN is trained, the on line faulted signal can be inputted into the ANN, the output of ANN is the fault diagnosis result.

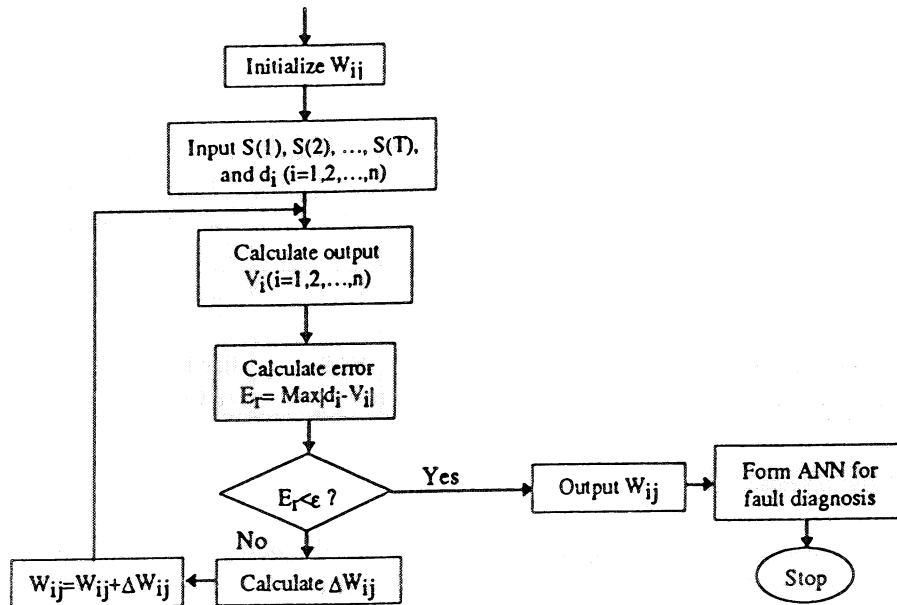


FIGURE 4. Flow Chart of ANN Adaptive Wavelet Fault Diagnosis

## THE APPLICATION IN FAULT ANALYSIS

### Test system training data and testing data

The space station power system architecture is shown in Figure 1. The system data is given in Table 1. System fault locations are classified into eleven patterns, which are listed in Table 2. For each case, fault is located along the line, specifically 25%, 50%, 75%, 100% from the sending bus to receiving bus. A total number of 44 cases were generated for the training of neural network. Another 44 faulted cases located at the 10%, 30%, 60%, and 80% of line length are generated for the test of ANN.

TABLE 1. Space Power System Data

<p><b><u>DDCU Parameters</u></b>  <math>K_v=200.0</math>, <math>V_m=160.0(v)</math>, <math>V_{out}=120.0(v)</math>, <math>\eta=95\%</math></p> <p><b><u>Input Circuit:</u></b>  <math>L_{11}=0.704(\Omega)</math>, <math>L_{12}=0.5(\Omega)</math>, <math>C_{11}=0.25(\Omega)</math>, <math>C_{12}=0.2(\Omega)</math>, <math>R_{11}=0.001(\Omega)</math>, <math>R_{12}=0.001(\Omega)</math>, <math>R_{13}=0.005(\Omega)</math>, <math>R_{14}=0.005(\Omega)</math></p> <p><b><u>Output Circuit:</u></b>  <math>L_{o1}=0.005(\Omega)</math>, <math>C_{o1}=0.0015(\Omega)</math>, <math>C_{o2}=0.0015(\Omega)</math>, <math>R_{o1}=0.5(\Omega)</math>, <math>R_{o2}=0.01(\Omega)</math>, <math>R_{o3}=0.3(\Omega)</math>, <math>R_{o4}=0.001(\Omega)</math></p>
<p><b><u>Load data (W):</u></b>  <math>P_{81}=250.0</math>, <math>P_{82}=500.0</math>, <math>P_{83}=750.0</math>, <math>P_{84}=1000.0</math>  <math>P_{85}=1600.0</math>, <math>P_{86}=750.0</math>, <math>P_{87}=500.0</math>, <math>P_{88}=250.0</math></p>
<p><b><u>Line data (<math>\Omega</math>):</u></b>  <math>R_{46}=0.001</math>, <math>L_{46}=0.0002</math>, <math>R_{671}=0.0376</math>, <math>L_{671}=0.00136</math>, <math>R_{672}=0.0376</math>, <math>L_{672}=0.00136</math>  <math>R_{7181}=0.00416</math>, <math>L_{7181}=0.000051</math>, <math>R_{7182}=0.00378</math>, <math>L_{7182}=0.000034</math>, <math>R_{7183}=0.00278</math>, <math>L_{7183}=0.000034</math>, <math>R_{7184}=0.00178</math>, <math>L_{7184}=0.000034</math>  <math>R_{7285}=0.00116</math>, <math>L_{7285}=0.000051</math>, <math>R_{7286}=0.00278</math>, <math>L_{7286}=0.000034</math>, <math>R_{7287}=0.00378</math>, <math>L_{7287}=0.000034</math>, <math>R_{7288}=0.00416</math>, <math>L_{7288}=0.000034</math></p>

### System fault analysis

The fault is assumed to be on a line to ground, and the fault resistance is set to be 0.1  $\Omega$ . The fault duration is 5ms. The time simulation program is used to simulate the system faulted current at the output terminal of DDCU. The DDCU model can be

found in (NASA, Lewis Research Center, 1993). Load is modeled as a constant impedance, whereas the line as R-L series circuit model. For each fault, the different locations along the line are simulated to form the training data of ANN.

TABLE 2. Fault Location Classification

Fault No.	Fault along	Fault No.	Fault along	Fault No.	Fault along	Fault No.	Fault along
F# 1	line from bus 4 to bus 6	F# 4	line from bus 71 to bus 81	F# 7	Line from bus 71 to bus 84	F# 10	line from bus 72 to bus 87
F# 2	line from bus 6 to bus 71	F# 5	line from bus 71 to bus 82	F# 8	line from bus 72 to bus 85	F# 11	line from bus 72 to bus 88
F# 3	line from bus 6 to bus 72	F# 6	Line from bus 71 to bus 83	F# 9	line from bus 72 to bus 86		

### Wavelet - ANN Fault Diagnosis

Weight - based architecture shown in Figure 6 is used for fault diagnosis. The same ANN topology with different weight architectures is used to classify different fault pattern. For  $N$  patterns of faults,  $N$  different architectures are used. Each architecture has one output with two desired values of 1 and 0. The weights of architecture (Arch)  $i$  ( $i=1, 2, \dots, N$ ) is trained in the way that the output of the architecture is close to 1 for  $F\# i$  and zero for other fault patterns. When the faulted signal of  $F\# i$  is inputted to the fault diagnosis ANN, only the output at architecture  $i$  is close to 1, the outputs at other architectures are close to zero. Therefore, the fault diagnosis is conducted by checking the outputs of the architecture.

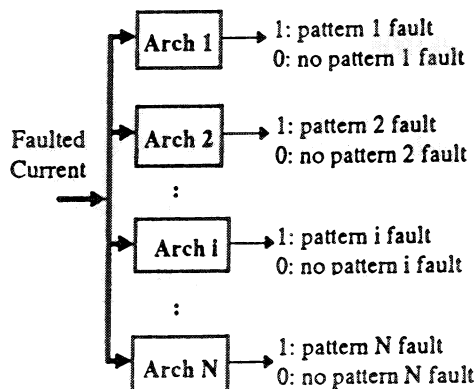


FIGURE 6. Wavelet - ANN Fault Diagnosis Architecture

Three patterns of faults ( $F\# 1$ ,  $F\# 2$ , and  $F\# 4$ ) are used to explain our fault diagnosis scheme. Figure 7 shows the faulted currents at DDCU output terminal for faults #1, #3, and #4. The fault is a short-time event, the faulted currents are oscillatory and have amplitudes that quickly decay to steady values. The feature meets the conditions of wavelet transform technique. The faulted currents at different locations are different. These faulted currents are used for the training of ANN. Figure 8 shows the weights for the different faulted currents and the outputs of the corresponding architectures. It can be seen that the weights and the outputs of architectures for different faults are quite different which makes it possible for fault diagnosis. Since the different fault has different wavelet transform factors, when these transform factors are integrated in the training of architecture weights, the different architecture weights will be got for different fault pattern. Different weights will produce different outputs, the fault diagnosis can be carried out by checking the outputs of architectures. For a given fault pattern, only one output has value close to 1. For example, when faulted current of  $F\# 1$  is inputted in the fault diagnosis ANN, the output of architecture 1 is close to 1 (1.109088), while the outputs of architectures 2 and 4 are close to zero (-0.070575 and 0.06069). Table 3 shows the output values of Wavelet - ANN diagnosis for faulted currents of  $F\#1$ ,  $F\#2$ ,  $F\#3$ , and  $F\#4$ .



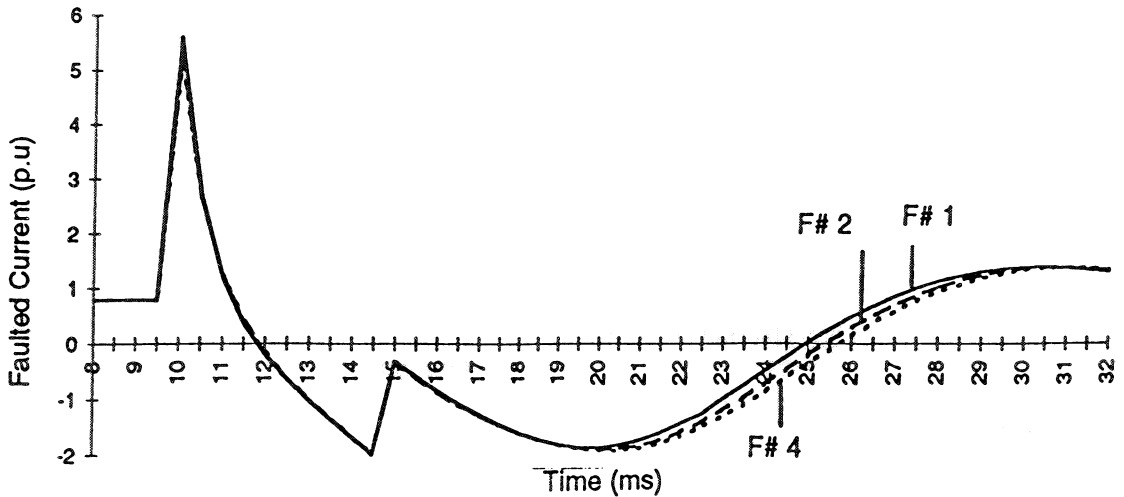


FIGURE 7. Fault currents at output terminal of DDCU (Faults # 1, # 2, # 4)

Table 4 displays the system fault diagnosis results. Since the system has eleven fault patterns, eleven architectures with different weights are used for system fault diagnosis. In this table, True (T) means that the output of ANN according to the fault pattern is close to 1 and the fault diagnosis result is correct, while, Failure (F) means that the output of ANN according to the fault pattern is far from 1, and the fault diagnosis is wrong. It can be seen that the neural network can identify the faults beyond the 10% length of the most lines. When the fault occurs near to the sending end bus, since the resistance of this section of line is very small, the faulted current is very close to the faulted current at sending end bus. Therefore, the neural network cannot identify the fault correctly. This region is a dead band of the diagnosis. Also, it can be seen that, for line 6-71 and line 6-72, the fault classifications are not as accurate as the other cases, since the two lines have same parameters, the faulted currents are very close when the fault occurs near the sending bus (bus 6).

TABLE 3. The Output Values of Fault Diagnosis ANNs

	$V_1$	$V_2$	$V_3$	$V_4$
F# 1	1.109088	-0.070575	0.07486	0.06069
F# 2	0.005727	0.960932	0.04939	0.09996
F# 3	0.027072	0.815518	0.01037	0.03019
F # 4	0.002880	-0.11091	0.11548	1.15519

TABLE 4. System Fault Diagnosis Results

Fault Pattern	10%	30%	60%	80%
F# 1	T	T	T	T
F# 2	F	F	T	T
F# 3	F	F	T	T
F# 4	F	T	T	T
F# 5	F	T	T	T
F# 6	F	T	T	T
F# 7	F	T	T	T
F# 8	F	T	T	T
F# 9	F	T	T	T
F# 10	F	T	T	T
F# 11	F	T	T	T

\* T: Fault diagnosis is correct, F: Fault diagnosis is wrong

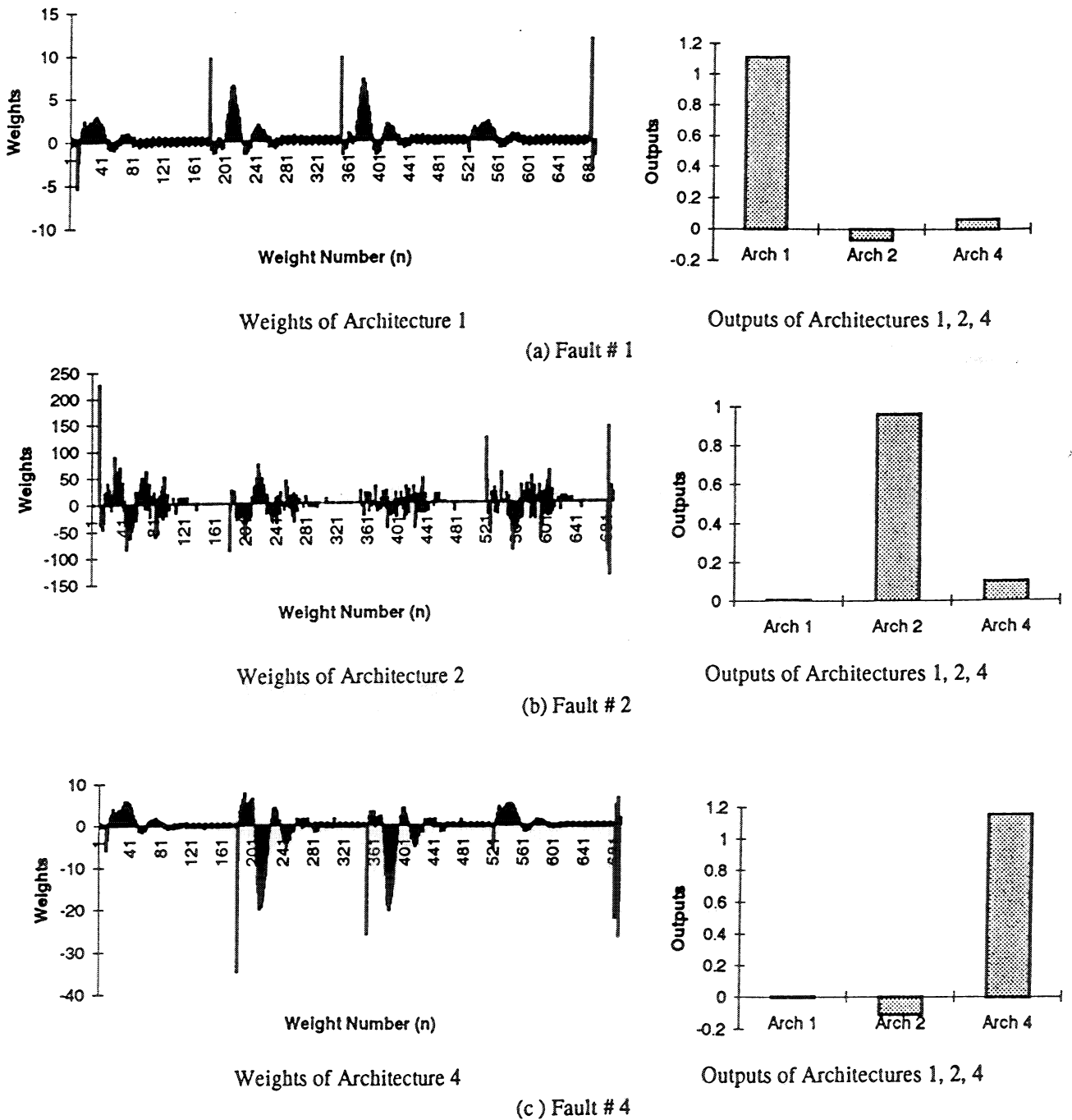


FIGURE 8. Architecture Weights and Outputs for Different Fault Patterns

## CONCLUSION

In this paper, we have discussed how wavelet transform coefficients can be adaptively computed in the training stage of ANN. This neural network adaptive wavelet scheme is applied to the fault diagnosis of space station power system. The architecture weights are trained adaptively for different fault patterns. The test results show that about 85-90% of the line fault can be identified by the proposed neural network efficiently. In the proposed scheme, the fault feature extraction stage is integrated into the training stage of ANN, which is much helpful for the on-line application. For on-line application, faulted signals are directly inputted to ANN for the training instead of a complex processing of all faulted signals.

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# Astro-E hard X-ray detector

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## ABSTRACT

Astro-E is the X-ray satellite to be launched in year 2000 by Inst. of Space & Astronautical Science. This report deals with the design and expected performance of the Hard X-ray Detector (HXD), one of the 3 experiments aboard Astro-E. The HXD is a combination of GSO/BGO well-type phoswich counters and silicon PIN diodes: the two combined will cover a wide energy band of 10–700 keV. The detector is characterized by its low background of  $\sim 10^{-5}/\text{s}/\text{cm}^2/\text{keV}$  and its sensitivity higher than any past missions between a few 10 keV and several 100 keV. Combined with the other 2 experiments, a micro-calorimeter array (XRS) and 4 CCD arrays (XIS), both with X-ray mirrors, the mission will cover the soft and hard X-ray range at a highest sensitivity.

**Keywords:** X-ray astronomy, hard X-ray detector, phoswich counter, silicon PIN diode, Astro-E

# 1 ASTRO-E PROJECT

The fifth Japanese X-ray astronomy satellite, ASTRO-E, following *Hakucho*, *Tenma*, *Ginga*, and *ASCA*, is scheduled for launch in year 2000 by the new launcher M-V-4 of Institute of Space and Astronautical Science from ISAS Kagoshima Space Center.<sup>1</sup> This satellite will carry three experiments: the Hard X-ray Detector (HXD) covering the energy band from 10 keV to 700 keV; a micro-calorimeter array with an X-ray mirror (X-ray Spectrometer - XRS); 4 CCDs with 4 X-ray mirrors (X-ray Imaging Spectrometer - XIS). The latter two experiments cover the soft X-ray band with the highest energy resolution<sup>2</sup> (micro-calorimeter:  $\Delta E \sim 12\text{eV}$ ), or with good energy resolution<sup>3</sup> (CCDs:  $\Delta E \sim 150\text{eV}$  at 5.9keV), both with imaging capability. All 3 experiments combined, Astro-E will become a spectrometer facility covering the energy band from 0.4 keV to 700 keV with good to moderate spatial resolution (XRS/XRT and XIS/XRT:  $\sim 1$  arcmin., HXD:  $\sim 20$  arcmin.).

The total weight and power available for the 3 experiments will be about 800kg and 200W, respectively. The M-V rocket will put the satellite into a near-circular orbit of radius 550km with an inclination of 31 deg. The 3 scientific instruments, the X-Ray Spectrometer (XRS) with an XRT (focal length  $\sim 3.5\text{m}$ ), the 4 X-ray Imaging Spectrometers (XIS) with an XRT each (focal length  $\sim 4.5\text{m}$ ), and the HXD, have adopted several new and inovative technologies. The micro-calorimeter array made of 36 HgTe elements will be the first such instrument to fly in a satellite and will have the ultimate energy resolution ( $\sim 12\text{eV}$ ) in the soft X-ray band.<sup>2</sup> The XRTs will be made of replica foils and will allow 1 arcmin. spatial resolution despite their light weight.<sup>4</sup> The X-ray CCDs will have deeper depletion region ( $\sim 80 \mu\text{m}$ ) and their energy resolution (fwhm) will reach the theoretical limit for the CCD: below 55eV at Oxygen K-line and 145 eV at 5.9 keV.<sup>3</sup> The large ( $\sim 20\text{mm} \times 20\text{mm}$ ) 2mm-thick silicon PIN diodes used in the HXD will be the first of this kind and will give us an energy resolution about 3keV (fwhm) in the hard X-ray band ( $\sim 10$  to 70 keV). The well-type phoswich counter itself is a new concept and will use a newly developed fast and high light-yield inorganic scintillators GSO(Ce) in its detection part.<sup>5 6 7</sup> These instruments will be prepared by ISAS, Univ. of Tokyo, Osaka Univ., Kyoto Univ., Nagoya Univ., Tokyo Metropolitan Univ., RIKEN, NASA/GSFC, Univ. of Wisconsin, and MIT.

The time schedule of the project is as follows: the R/D works have nearly been completed in Japanese FY 1995, the Engineering Model (EM) of crucial items with its associated electronic circuitry have been produced and tested in the spring of 1996. Based on these tests and R/D works, the design will be frozen in the fall of 1996 and production of the Flight Model (FM) will begin early 1997. The FM will then be completed in mid-1998 followed by the final assembly and tests. The launch date is set at present late in Japanese FY 1999 or in the winter of calender year 2000.

## 2 ASTRO-E HARD X-RAY DETECTOR

The Astro-E HXD<sup>8 9</sup> has been jointly developed by scientists at Department of Physics, University of Tokyo, Institute of Space and Astronautical Sciences (ISAS), Institute of Physical and Chemical Research (RIKEN), National Laboratory for High Energy Physics (KEK), and others. It is basically an upgraded version of the well-type phoswich counters successfully flown on balloons.<sup>10 11 12 13 14 15</sup> Silicon PIN diodes are the important addition introduced to lower the energy coverage as well as to improve the energy resolution in the lower energy band. The design and characteristics of the HXD as of June 1996 are described here together with its expected performances.

The HXD detector assembly is schematically shown in Fig. 1. The total weight of this assembly will be about 200 kg including the electronic part not shown in the figure. The HXD consists of 16 ( $=4 \times 4$ ) modular units and has an overall photon collecting area of about 330  $\text{cm}^2$ . Each unit is built around a phoswich counter made of a fast inorganic scintillator, GSO ( $\text{Gd}_2\text{SiO}_5:\text{Ce}$  0.5% mol)<sup>5 6 7</sup> and the BGO active shield as shown in Fig. 2. Cosmic hard X-rays are detected as clean-hits if their full energy is deposited in the fast scintillator GSO. The active collimation part of the BGO shield forms four deep-wells (320mm deep,  $\sim 25\text{mm} \times 25\text{mm}$  in area), limiting the field of view to  $\sim 4.3^\circ \times 4.3^\circ$ . The GSO crystals (four per unit, each measuring in area 24 mm  $\times$  24 mm and in thickness 5 mm) are glued at the bottom surface of the wells. The

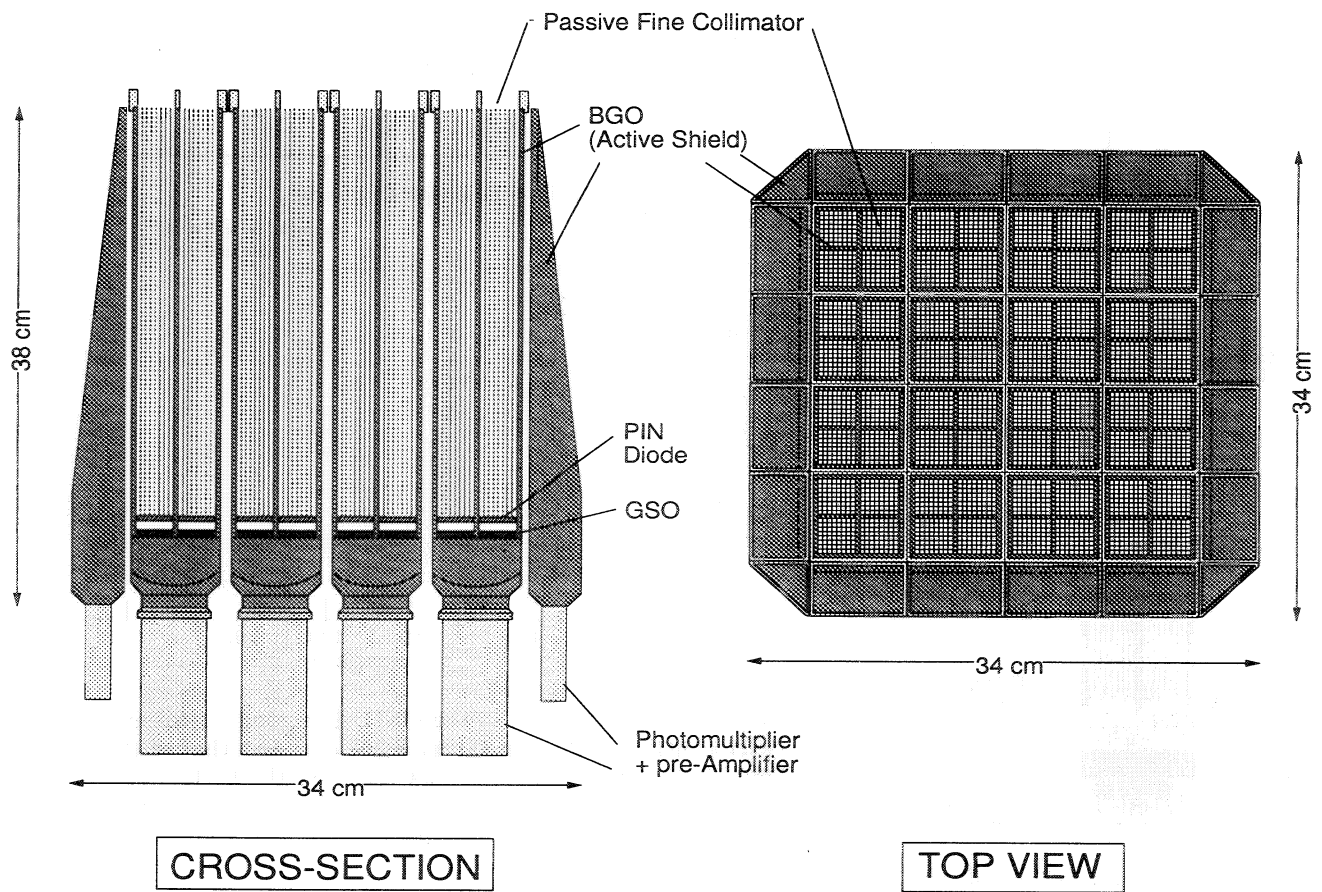


Figure 1: The HXD detector assembly: Cross-section (left) and the top view (right). The housing and most of the electronic part are not shown here.

entire assembly is viewed by a 2-inch phototube from the exterior surface of the shielding part.

The silicon PIN diodes, each with an active area of  $20\text{ mm} \times 20\text{ mm} \times 2\text{ mm}$ , are assembled in a unit of two layers and placed in the deep BGO well just above the detection part (Fig. 2). Two PIN diodes are placed per well, making a total of eight per unit. The HXD contains 128 Si diodes in all, achieving a photon collecting area of about  $230\text{ cm}^2$ .

Each group of 4 detector units will be equipped with an independent high voltage supply for the phototube, and a common DC power supply for 8 PIN diodes. Fig. 3 shows the effective areas of the phoswich scintillators and the silicon PIN diodes, in the respective energy ranges of  $40 - 700\text{ keV}$  and  $10 - 70\text{ keV}$ .

The  $4 \times 4$  matrix of phoswich counters are surrounded by 20 units of thick BGO anti-counters for additional shielding. Furthermore, a fine collimator made of phosphor bronze sheet ( $50\mu\text{m}$  thick) is placed inside the BGO wells to match the HXD field of view to that of the soft X-ray telescopes ( $17 \times 17\text{ arcmin}^2$ ). This collimator is expected to reduce the the cosmic diffuse X-ray background that may otherwise become a dominant background source for the PIN diodes. In the soft  $\gamma$ -ray band, background is reduced by mutual anti-coincidence among neighboring units. We expect the detector background to be below  $10^{-5}\text{ c/s/cm}^2/\text{keV}$  for the Si PIN diodes and  $\sim 10^{-5}\text{ c/s/cm}^2/\text{keV}$  for the scintillators.

The estimated sensitivity will be set by the background due to the radioactivity induced within the counters while in the orbit. It will be substantially better if the detector is flown in a lower orbit (eg. that of CGRO), where activation is much less. than the ultimate limit the well-type phoswich counter can attain. Lowering the background and knowing its origins are crucial in the following respect: We plan to avoid the

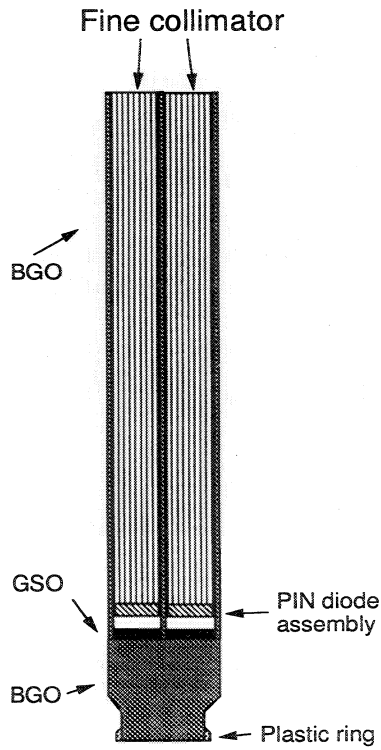


Figure 2: Cross-section of one HXD detector unit.

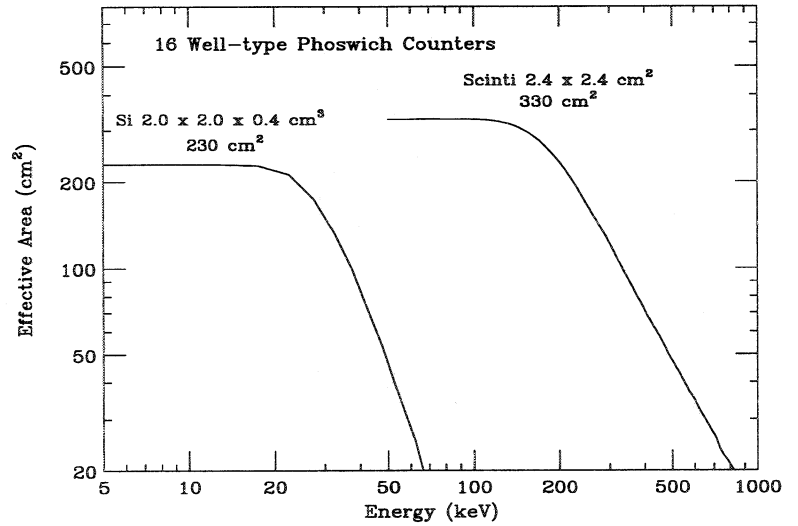


Figure 3: Effective area of the HXD: The geometrical area of the GSO scintillators (5 mm thick) is 368 cm<sup>2</sup> and that of the silicon PIN diodes (4 mm thick) is 256 cm<sup>2</sup>. With the fine collimator, the two effective areas are reduced by about 10 % to become 330 cm<sup>2</sup> and 230 cm<sup>2</sup>, respectively.

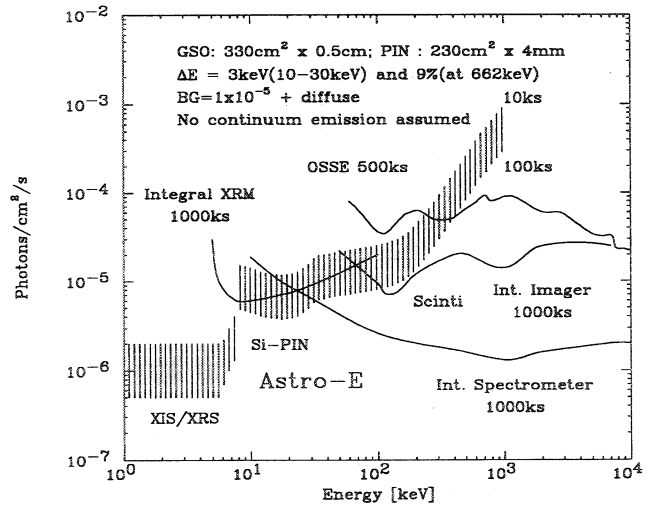
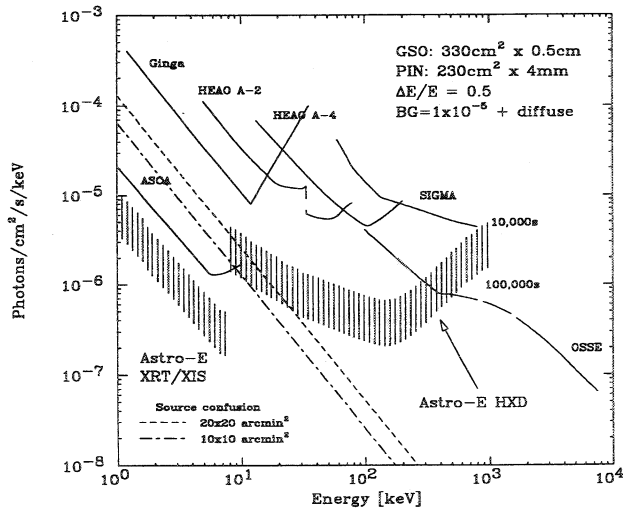


Figure 4: Sensitivities ( $3\sigma$ ) to the continuum (left) and line (right) emissions of Astro-E HXD and selected missions.

ON-OFF subtraction by estimating the background accurately ( $\sim$  a few %) from monitor counts as was done in the Ginga LAC observations.<sup>16</sup>

In Fig. 4, the expected  $3\sigma$  sensitivities to the continuum and to the line emission of Astro-E HXD are compared with those of the past and planned satellite missions. The sensitivity of Astro-E HXD for point sources will be substantially higher than any other past missions in the energy band between 10 keV to several 100 keV. We therefore expect to detect and study many new cosmic hard X-ray point sources. The Astro-E HXD, on the other hand, will have only a modest sensitivity to diffuse gamma-ray emissions such as the 511 keV line distributed over the Galactic ridge.

## 2.1 Well-Type Phoswich Array

The phoswich counter consists of two kinds of scintillators whose scintillation decay times are distinctly different. The faster scintillator is placed in the front as the detection part and the slower one in the back as the shielding part. The phototube signals generated purely by the faster scintillator are selected by using an appropriate pulse-shape discriminator (PSD). Signals with an appreciable contribution from the slower scintillator, eg. those of hard X-rays scattered by the shielding part and those of charged particles penetrated through the shielding part, are efficiently rejected (see Sec.4.3). This phoswich technique has been used for many years in cosmic  $\gamma$ -ray detection. The uniqueness of the “well-type” phoswich counters is that the well-shaped shielding part acts also as an active collimator and that each counter filters out, quickly and effectively, unwanted hard X-rays down if even only a small energy (50 – 100keV) is deposited in the collimator and shielding part.<sup>10 12</sup> The detection part (the fast scintillator) being buried deep in the active anti-coincidence well also reduces efficiently background due to nuclear activity. The details on the development of the well-type phoswich counter are given elsewhere.<sup>10 11 12 13</sup>

Choice of the two scintillation materials becomes important in reducing the background and improving energy resolution. For its large effective atomic number and long scintillation decay time, BGO emerged as the choice for the shielding part. Through a test on a prototype well, we noted that BGO commercially available at that time was contaminated by a radioactive isotope  $^{207}\text{Bi}$ .<sup>17 18 12</sup> A prior report existed finding that the amount of contamination largely depends on where the Bi ore comes from.<sup>18</sup> The BGO scintillators now commercially available have substantially reduced  $^{207}\text{Bi}$  contamination.<sup>19</sup>

Radioactive contamination (natural and induced) in the detection part contributes to the background more directly and should be absolutely minimized. Radioactive contamination has been measured for two high-light-yield scintillation materials with fast decay times, GSO(Ce)<sup>5 6</sup> and YAP(Ce)<sup>20 21</sup> (see Table 1), and their activation characteristics have been studied by irradiating them with protons of kinetic energies typical to the satellite orbit ( $\sim$ 100 MeV).<sup>10 12 22 23</sup> The study has shown that the number of long-life line  $\gamma$ -rays in the energy range of HXD is comparable for 2 cm thick YAP and 5 mm GSO for a fixed dose of proton. Note that the radiation length is quite different for the two crystals (see Table 1). We found recently that scintillation light yield decreases as temperature drops below 0°C for YAP but increases for GSO as shown in Fig. 5.<sup>7</sup> We also found that a slowly decaying scintillation component becomes dominant below 0°C for YAP.<sup>7</sup> We plan to set the operating temperature at around  $-15 \sim -20^\circ\text{C}$  so that the leakage current of the PIN diodes be reduced: hence GSO(Ce) became our final choice.

We have already received about 40 GSO scintillators from Hitachi Chemical: their light yield are around 30% of a typical NaI(Tl) and give about  $\Delta E(fwhm) \simeq 6.8 - 7.5\%$  at 662 keV when directly coupled to the PMT. When viewed through the BGO well, the resolution deteriorates typically to  $\simeq 9.5\%$  at 662 keV at room temperature. Since the light yield is expected to increase by about  $\sim 15\%$  in the operating temperature ( $-20^\circ\text{C}$ ) as seen in Fig. 5, we expect the resolution to be around  $\Delta E(fwhm) \simeq 8.8\%$  or  $\simeq 7\%/\sqrt{E[\text{MeV}]}$ .

### 2.1.1 Fine collimator

The two other experiments in the Astro E mission focuss on fine spectroscopy with imaging capability and have a narrow field of view (FOV) of around  $17 \times 17$  arcmin<sup>2</sup>. The FOV of HXD is determined by

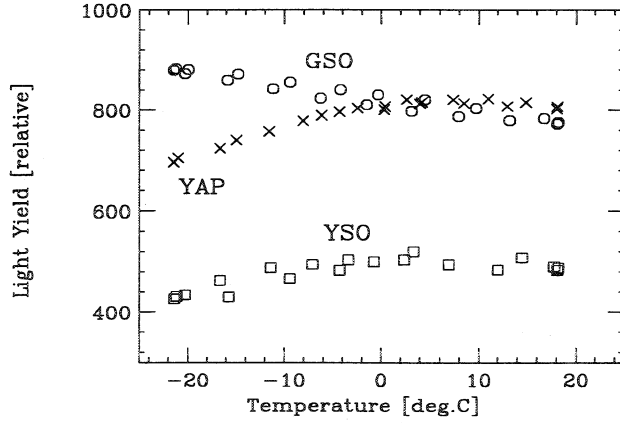


Figure 5: Temperature dependence of light yield for GSO, YSO and YAP when measured with a shaping amplifier with 500 ns time constant.

Table 1: Characteristics of NaI, BGO, GSO and YAP

	NaI(Tl)	BGO	GSO(Ce)	YAP(Ce)
Chemical composition	NaI (Tl)	Bi <sub>4</sub> Ge <sub>3</sub> O <sub>12</sub>	Gd <sub>2</sub> SiO <sub>5</sub> (Ce)	YAlO <sub>3</sub> (Ce)
Eff. atomic number	50	74	59	35
Density (g/cm <sup>3</sup> )	3.7	7.1	6.7	5.5
Rad. length (cm)	2.6	1.2	1.4	2.6
Index of refraction	1.85	2.15	1.9	1.94
At around 20°C				
Decay time (ns)	~230	~300	~60	~30
Light yield (relative)	100	~12	~28	~35
Peak emission (nm)	410	480	430	347
At around -20°C: data on GSO and YAP are preliminary.				
Decay time (ns)	~500	~600	~80	~30 and > 500
Light yield (relative)	~75	~15	~30	~20
Peak emission (nm)				

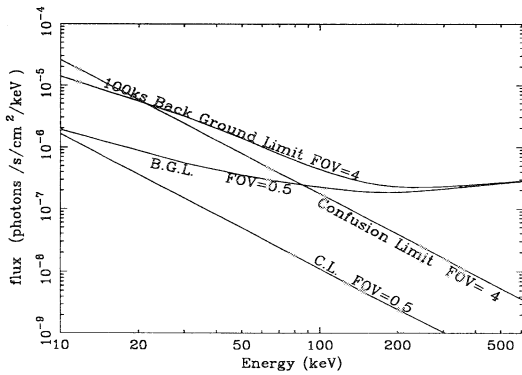


Figure 6: Limit to the sensitivity set by the diffuse background (B.G.L.) and source confusion (C. L.), with the  $8 \times 8$  fine collimator (FOV=0.5) and without (FOV=4).

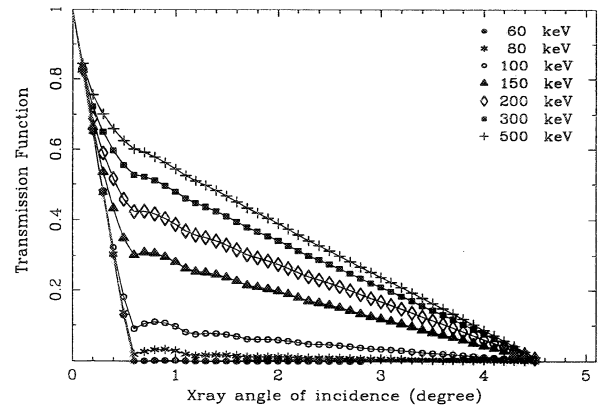


Figure 7: Transmission function of the fine collimator.

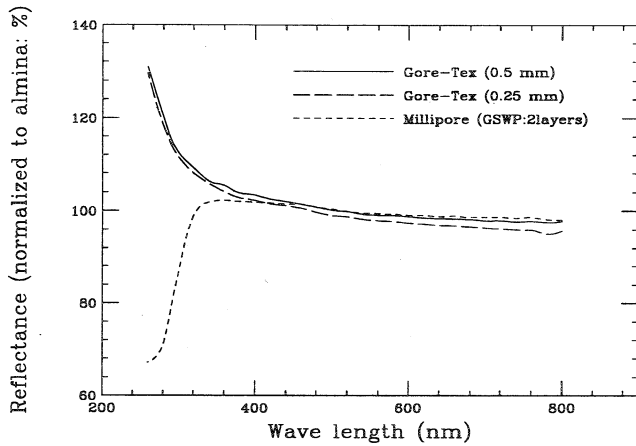


Figure 8: Reflectivity of reflective sheets as a function of wavelength.

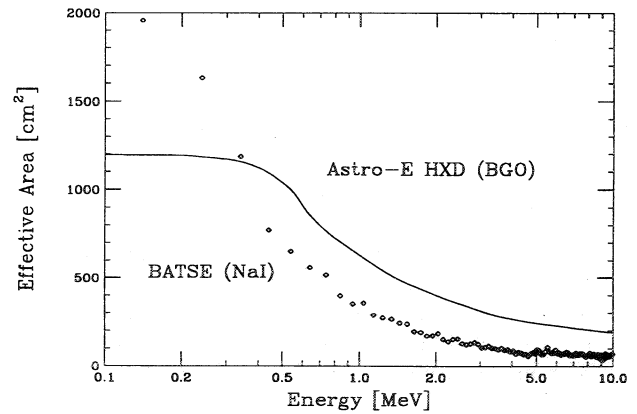


Figure 9: Effective area of one of the 4 anti-counter planes used as the  $\gamma$ -ray burst detector (BGO 2.6 cm) compared with that of BATSE one unit.

the depth of the BGO well and the cell size of the fine collimator, both of which are in principle adjustable. In practice, however, the mechanical stability and availability of the BGO crystal set a limit at around the present value of 32 cm. The transverse dimension of the detection part is required to be substantially larger than the depth, setting the FOV at around 4.3 deg. At the low background rate of the well-type phoswich counter, the sensitivity will then be limited by the source confusion and diffuse background for the 4.3 deg FOV up to about 100 keV (see Fig. 6).<sup>24</sup> The passive fine collimator has been designed to reduce the source confusion and diffuse background.<sup>24</sup>

The collimator is made of phosphorus bronze sheets spot-welded to form 30 cm long  $8 \times 8$  cells. The thickness of the phosphorus bronze sheets is  $50 \mu\text{m}$  which gives a narrow FOV below 100 keV but secures an order of magnitude wider FOV for the 511 keV line (see Fig. 7).

The challenge we now face is accuracy of the cell-to-cell alignment as well as the mutual alignment of the 4 collimators in a detector unit. Possible nuclear activation of phosphorus bronze in orbit also concerns us and will be studied by irradiating the material with 100 MeV protons.

### 2.1.2 UV-transparent epoxy and reflector

The shielding part (the well and the bottom in Fig. 2) is made of seven BGO plates and a BGO block: they are glued together by epoxy resin transparent in  $\lambda \sim 350 - 600$  nm, EpoTek 301-2 by Epoxy Technology Inc.<sup>25 26</sup> The detection part, GSO, is glued by silicon compound KE103 by Shin'Etsu Chemical<sup>27</sup> that can absorb the difference in the expansion coefficients of BGO and GSO ( $\sim 10^{-5}$  in one axis). It is also transparent in the wavelength range.<sup>25</sup>

The scintillator assembly is then wrapped by a light reflector sheet that has a high reflectance in the wave band and chemically stable. Our test has shown that the white GorTex sheet<sup>28</sup> has the best reflectance as shown in Fig. 8.

## 2.2 Anti-Counters

The anti-counters serve primarily to guard the 16 well-type phoswich counters from nuclear particle bombardment and to reduce the background in the phoswich counters (see Fig. 1). They are made of BGO and have wedge shapes as shown in the figure. Combination of these 20 anti-counters and the shielding parts shields all GSO scintillators with at least  $\sim 5$  cm of BGO all around. This reduced the cosmic proton flux

on the GSOs by an order of magnitude.<sup>23</sup> The anti-counters also serve to reduce Compton scattered events as well as nuclear activation background events.

The total area covered by these thick BGO anti counters (2.6 cm in average) is quite impressive: each face has a geometrical area of  $\sim 1200 \text{ cm}^2$ , and an effective area at 1 MeV of  $\sim 600 \text{ cm}^2$  as shown in Fig. 9. We plan to use all 4 faces to monitor  $\gamma$ -ray bursts and transient phenomena. By comparing the counts in the 4 faces, we will be able to determine the direction to  $\sim 5^\circ$ .

Because of the scintillator shapes, we do not expect a good energy resolution in this monitor. The energy range coverage, on the other hand, will be quite wide as shown in Fig. 9. The scintillator used (BGO) is relatively fast and allows us to record transient phenomena in fine time bins (1/64 ms) as will be discussed in Sec.4.1. We believe this will be quite important when locating  $\gamma$ -ray bursts by the arrival times registered by 3 or more satellites, one being Astro-E.

## 2.3 Silicon PIN Diode

In the well-type phoswich counter, two layers of 2 mm thick PIN diodes sit in front of the GSO scintillators. Softer X-rays will be photo-absorbed in the two layers of PIN diodes, while harder photons pass through the two diode layers and reach the GSO crystal (see Fig. 3).

The PIN diodes are introduced to fill the possible gap in the energy coverage between the phoswich counters ( $\geq 50 \text{ keV}$ ) and the CCDs ( $\leq 10 \text{ keV}$ ). The BGO wells provide the PIN detectors with a very low background environment and the diodes, in return, act as anti-coincidence shields for the scintillators against low-energy charged particles. The background level is expected to be substantially lower than  $10^{-5} \text{ /sec/cm}^2/\text{keV}$  for the PIN diodes.

There are several technically critical issues in developing thick PIN diodes. One needs ultra high purity ( $\sim$  ultra high resistivity) silicon wafers that give little volume leakage current.<sup>8 29 30</sup> Even with such wafers, extreme care must be taken in the diode fabrication process not to increase edge leakage current nor to lower the breakdown voltage.<sup>31 32</sup> Sample diodes with thickness of 1-1.5 mm have been produced by Hamamatsu, Micron, and Seiko Instruments Inc.<sup>31 32</sup> We plan to develop 2 mm thick diodes and stack two of them to obtain 4 mm effective thickness. To reduce the leakage current to a reasonable level ( $<$  a few nA), we plan to operate HXD at around  $-20^\circ\text{C}$ .

## 2.4 Low Noise Charge Amplifier

Improving the energy resolution is the most demanding issue in developing our silicon PIN diode. The energy resolution can be improved by optimizing the design of the preamplifier and the shaper amplifier. In reality, however, the total input capacitance ( $C_{in}$ ) which is the sum of the junction capacitances of two PIN diodes ( $\sim 2 \times 20 \text{ pF}$ ) and the capacitance of the cables connecting the diodes to the preamplifiers ( $\sim 30 \text{ pF}$ ) will determine the resolution.<sup>8 29 30</sup> We currently set our goal at an energy resolution of  $\Delta E(fwhm) \simeq 3 \text{ keV}$  at  $-20^\circ\text{C}$  and are developing a low-power low-noise amplifier system optimized to this large input capacitance. The current design gives the equivalent noise figure shown in Fig. 10.

# 3 HOUSING OF THE DETECTOR ARRAY

The mechanical vibration and shock is expected to be much higher for the M-V rocket of ISAS than for rockets powered by liquid fuel and the housing for the detector array requires great care. The dissipation of the heat generated by the AE parts placed in the housing ( $\sim 15 \text{ W}$ ) poses additional constraint to the design. Since the BGO crystal is quite brittle, some support mechanism must be installed to damp external vibrations and to minimize the internal stress of BGO. The thermal expansion coefficient of BGO is an order



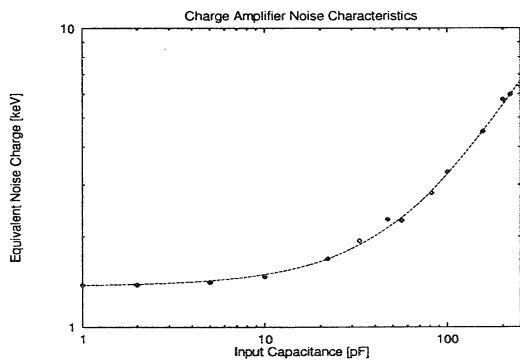


Figure 10: Equivalent noise count (ENC) of the preamplifier for PIN diodes.

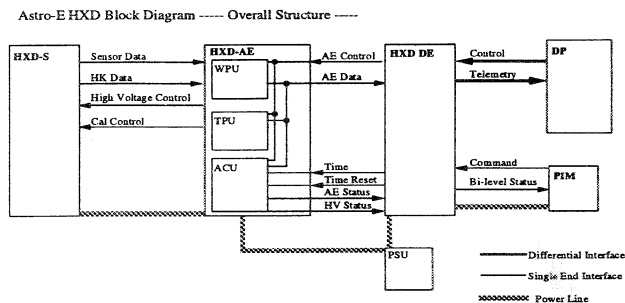


Figure 11: Block diagram of the HXD electronics

of magnitude smaller than any metal and consequently some critical parts will be made of carbon fiber or glass fiber reinforced plastic composite.

The detector array will probably be serviced including replacement of some detector units. This requires each unit to be mechanically independent. On top of all the above, the total amount of passive material must be minimized because of background generated by bombardment of cosmic protons and neutrons.

## 4 ELECTRONICS AND DATA ACQUISITION

The electronic system for the Astro-E HXD consists of the analog electronics part (AE) and the digital electronics part (DE)<sup>9</sup> as shown in Fig. 11. The AE consists primarily of pulse shape discriminators (PSD) and circuits associated with ADCs. The DE formats and processed the digitized data. The final data are then transmitted to the ground stations under control of DE. Data from various environmental monitors will also become critical in the HXD analysis, because the scintillation light yield is known to be temperature dependent and reliable background subtraction requires accurate monitoring of possible background origins.

### 4.1 Analog Electronics

The AE consists of one control board (ACU) and eight signal-processing boards (see Fig. 11). The latter are broken into the following two types: WPU for the well-type phoswich counters and PIN diodes, and TPU for the anti counters. The ACU handles power supply to AE and monitors the house keeping data about power supplies, timing, temperatures, and others.

The analog signal is taken from the last or the second last dynode of the PMT in the well-type phoswich counter. It is first fed to a charge sensitive preamplifier placed in the detector housing and then to a pulse shape discriminator (PSD) in the WPU board. The anode signal of the PMT is used for a fast pre-trigger that generates the peak-hold gate for the PSD. The PSD selects signals whose time profiles are consistent with that of the detection part (GSO), and rejects those contaminated with slow-decaying BGO scintillation light. While in orbit, the counting rate in the shielding part will be 4-5 orders of magnitude higher than that of clean hits in the detection part. The PSD selects the clean hits by comparing the output pulse heights from the two shaping amplifiers with different integration times. The PSD has been developed as a semi-customed LSI to reduce the circuit size and power consumption.<sup>33 34 35</sup>

PIN diodes can also trigger the data acquisition system if a diode level discriminator detects a signal while no slow scintillation light is detected by the PSD for the phoswich unit housing the diode.

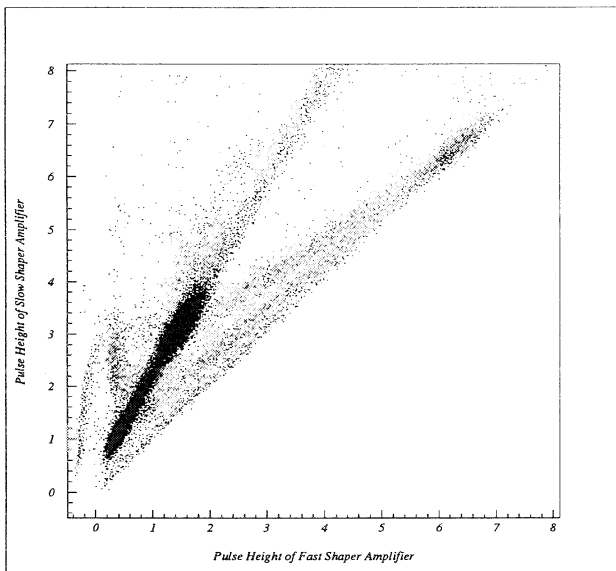


Figure 12: Correlation between the fast and slow shaper outputs ( $\tau = 100$  ns and 500 ns) obtained by the EM unit at  $-20^\circ$  deg. and the PSD LSI irradiated by 662 keV gamma-rays. See text.

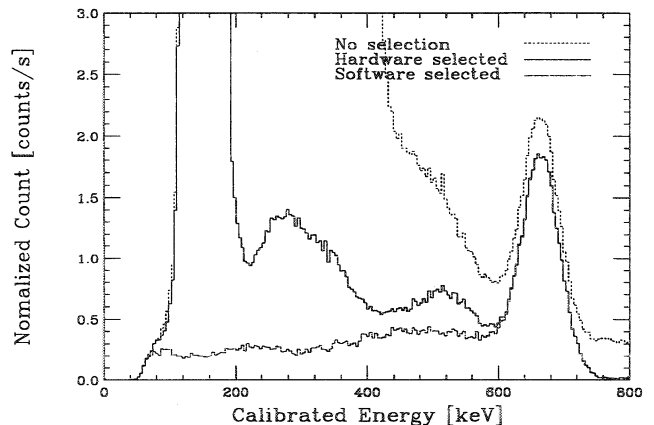


Figure 13: Pulse height distribution of the slow shaper output selected by the PSD gate and off-line filtering from Fig. 12. Since the data was taken with only one unit and in a temperature control box, gamma-rays escaped through the 3 mm BGO wall after hitting GSO and stray gamma-rays entered through the 3 mm BGO wall to hit GSO.

When a trigger is issued either by a PSD or a PIN diode, all analog outputs from the corresponding phoswich unit (those of the slow shaper, the fast shaper, and the four diode shapers) are digitized. The upper discriminator outputs (see below) and existence of any hits (the hit pattern) of all the 16 counters and 20 anti-counters are recorded together with the time of the event by the WPU board.

When large inorganic scintillators are used in the space as in the present case, highly ionizing nuclear particles often deposit energy higher than the saturation point of the amplifying system. They may potentially cause some erroneous response in the analog system. In the AE, we install discriminators to detect such events (the upper discriminators) and protect the analog system from such misoperation.

The signal from the 20 anti-counters are processed in units of five in the TPU boards. The outputs of all 20 lower discriminators are distributed to the WPU boards via the "hit pattern" bus. Signals are then summed to produce two sets of pulse height distributions: one has only 4 energy bins but renewed every 1/64 msec, and the other has 64 energy bins and renewed at 512 msec interval. These transient pulse height distributions are used to detect  $\gamma$ -ray bursts, various flare-ups, and other bright transient phenomena. Once a  $\gamma$ -ray burst occurs, for example, the on-board burst detection circuit or the program running in the CPU triggers the memory control circuit of the histogram buffer to record the time-resolved pulse height distributions of the burst for 128 seconds. We expect to detect about 160 bursts per year.

## 4.2 Pulse Shape Discriminator

The PSD distinguishes events from the two scintillators, the fast-decaying scintillator (GSO) and the slow-decaying scintillator (BGO). There are several PSD methods developed and used in  $\gamma$ -ray astronomy and nuclear physics, one of which being the double shaping method adopted in the HXD. In this method, the signal from a phototube is integrated with two different shaping times and the two output pulse heights are compared. This method is less affected by external electronic noise, while its demerit is that the circuit becomes somewhat complicated. This demerit can be solved by implementing the circuit on an LSI chip.<sup>33 34 35</sup> In our LSI chip, the two integration times are set at around  $\tau_{fast} = 100$  ns and  $\tau_{slow} = 500$  ns.

The outputs of the two shapers have different pulse heights for BGO signals, while they are almost equal for pure GSO signals. The pulse-shape discrimination LSI has been developed using a semi-customed LSI technology.<sup>33 34 35</sup> Shown in Figs. 12 and 13 is the result of a test done by using the LSI circuit with the phoswich unit of the Engineering Model: the irradiated gamma-rays are from  $^{137}\text{Cs}$  (662 keV). In Fig. 12, the linear cluster extending at an angle around 30 deg. to the ordinate, is due to hits on the BGO shielding part while the one extending to right is due to clean hits on the GSO detection part. Compton scattered gamma-rays form two linear clusters bridging between the blob corresponding to the clean hits on GSO and either one of the two blobs corresponding to the bottom BGO and the collimator BGO. One can see that pure GSO events can be separated from BGO events and Compton scattered events. Fig. 13 shows how the background is reduced by selection of the GSO cluster in Fig. 12 by the PSD chip and subsequent off-line analysis. Since we have put only one unit in a temperature- controlled box, Compton-scattered gamma-rays escaped or entered through the 3 mm BGO wall as apparent in Fig. 13. In the real detector, these  $\gamma$ -rays will be captured by neighboring units and rejected when the hit pattern is interrogated.

### 4.3 Digital Electronics

The DE controls acquisition of the data, coordinates among them, detects and reacts on requests for services, and provides the primary interface with the satellite data processor for command and telemetry (see Fig. 11). These tasks are executed by a system consisting of one Intel 80386 running at 8 MHz. To obtain a high data-acquisition rate, each AE board is capable of sending data by the DMA transfer mode to the DE. Here the data for 64 events are blocked so that the interrupt rate to CPU remains low.<sup>9</sup>

The CPU also performs some software event selections by examining the hit pattern around the unit in which the trigger is initiated: this further reduces Compton scattered events and particle interaction events. The CPU acquire calibration data and data used to estimate background.

## 5 CALIBRATION AND MONITORING

On board calibration will be needed in the energy measurement by the PIN diodes and phoswich detectors. For the diodes, we are examining possibility of using K X-rays from the phosphorus blonze of the fine collimator. For GSO, the  $\alpha$ -rays emitted by a natural isotope  $^{152}\text{Gd}$ , appearing at around  $E_\gamma \sim 385$  keV with a counting rate around  $\sim 10^{-4}/\text{s}/\text{cm}^2/\text{keV}$ , will be used.<sup>10 11 12 13 14</sup>

Critical items to be monitored include various counting rates that will be needed in estimating the activation background. The temperature of the scintillators and phototubes are also to be monitored because of their temperature dependence shown in Fig. 5.

## 6 EXPECTED BACKGROUNDS

Possible in-orbit backgrounds have been estimated for the present counter design: GSO of  $2.4 \times 2.4 \times 0.5$  cm<sup>3</sup> shielded by BGO of  $\sim 5$  cm thickness all around.<sup>22 8</sup> The proton flux has been assumed to be that of the model given in the reference<sup>23</sup> at the solar minimum, although the scheduled flight time corresponds roughly to the solar maximum when the background is expected to be about half.<sup>23</sup> The results are summarized in Table 2: one can see that the internal and cosmic-ray induced radioactivities will be the dominant source of background below 300 keV. We therefore anticipate that the sensitivity of HXD will be limited by these induced radioactivities.

Among the listed background origins, prompt backgrounds produced by charged particles on BGO can easily be rejected. Gamma-rays generated in passive material around the detector array have some chance to leak through a few centimeter of BGO, if their energy is above  $\sim 300$  keV. We have to minimize passive material close to the HXD detectors, eg. the HXD housing and the fine collimator. Gamma-rays generated

Table 2: Expected background rates

In-orbit activation	:	$\sim (0.5 \sim 1) \times 10^{-5} / \text{sec/cm}^2/\text{keV}$ at 100 keV
Leak-thru $\gamma$ -rays	:	$\sim 1 \times 10^{-6} / \text{sec/cm}^2/\text{keV}$ at 300 keV $\sim 2 \times 10^{-5} / \text{sec/cm}^2/\text{keV}$ at 400 keV $\sim 2 \times 10^{-4} / \text{sec/cm}^2/\text{keV}$ at 500 keV
Off-aperture CXB	:	$\sim 7 \times 10^{-6} / \text{sec/cm}^2/\text{keV}$ at 50 keV $\sim 1 \times 10^{-6} / \text{sec/cm}^2/\text{keV}$ at 100 keV
Radioactive impurities	:	$5 \sim 1 \times 10^{-6} / \text{sec/cm}^2/\text{keV}$ below 300 keV

by nuclear interactions in the tip of the XRT complex have some chance to enter the FOV determined by the BGO well.

What may become a dominant background and yet is difficult to estimate is faking of clean-hit GSO events by pile-up of BGO hits or by Cherenkov photons in the PMT face windows. Background due to radioactivity and amount of radioactivity that may be produced have been and still are actively studied by bombarding the materials around the HXD detector with protons and by running the simulation programs.<sup>22</sup> Through these efforts and adequate on board monitoring, we expect to be able to predict the background for actual observations to an accuracy better than  $\sim 5\%$ . We note that such predictions worked to about  $\sim 1\%$  level in the Ginga-LAC.<sup>16</sup>

## 7 CONCLUSIONS

The design and expected performance of the Hard X-ray Detector (HXD), one of the 3 experiments aboard Astro-E have been presented. Most of its critical elements have been prototyped, tested, and verified their validity. One item that still requires continuing R/D works is the 2 mm thick silicon PIN diodes. The total weight and the total power consumption are to be reduced further. We expect the above issues to be solved within this calendar year.

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